Quantum spin chains with various defects

Cosim a Schuster and Ulrich Eckern

Institut fur Physik, Universitat Augsburg, 86135 Augsburg, Germany Corresponding author: cosim a schuster@physik.uni-augsburg.de

A bstract. Using the density matrix renormalization group (DMRG) method, we study the quantum coherence in one-dimensional disordered spin chains and Ferm i systems. We consider in detail spinless ferm ions on a ring, and compare the in uence of several kinds of in purities in a gapless and a dimerized, gapped system. In the translation-invariant system a so-called site-in purity, which can be realized by a local potential or a modi cation of one link, increases for repulsive interaction, and decreases for attractive interaction, upon renormalization. The weakening of two neighbouring bonds, which is a realization of a socalled bond-impurity, on the other hand, is healed for repulsive interaction, but enhanced for intermediate attractive interactions. This leads to a strong suppression of the quantum coherence measured by the phase sensitivity, but not to localization. Adding a local distortion to a dimerized system, we nd that even the presence of a single site-impurity increases the metallic region found in the dimerized model. For a strong dimerization and a high barrier, an additional sharp maximum, is seen in the phase sensitivity as a function of interaction, already for system sw ith about 100 sites. A bond-impurity in the dimerized system also opens a sm all metallic window in the otherwise isolating regime.

K eyw ords: quantum spin systems, disordered wires PACS: 75.10 Jm, 75.40 Ng

1 Introduction

Recent experiments have led to a renewed theoretical interest in disordered spin-Peierls system s. For example, the doped one-dimensional H eisenberg system $Cu_{1 \times} Zn_x GeO_3$ [1] shows two subsequent magnetic transitions, the spin-Peierls transition at T = 14K followed by a transition to an antiferrom agnetic ground-state at $T_N = 5 K$, while in $Cu_1 \times Mg_x GeO_3$, a reentrant spin-Peierls phase for $x > x_c$ [2] is observed. In fact, the general question of the e ect of various types of in purities in pure [3, 4, 5, 6, 7, 8] or gapped spin system s [9, 10, 11] has been studied intensively during the last years. Nevertheless, the interplay between interaction, disorder, and periodic distortions is still a challenging problem. The model of spinless ferm ions, which is considered here in detail, is equivalent to the anisotropic Heisenberg model. It describes certain aspects of magnetic and electronic systems, and the phase diagram of this \sim plest" interacting ferm ion model is surprisingly rich. On the basis of this model, the aim of this work is thus to achieve a better understanding of the ground-state properties of disordered spin- and interacting Ferm i-system s, especially clarifying the role of the interaction, which may enhance or decrease the localization due to the random and periodic perturbations. In particular, we will introduce and compare the e ects of various kinds of im purities.

In this context, Eggert and A eck [3] pointed out that two \classes" of in purities exist, which di er in their e ect on the local symmetry of the system. So-called \site-in purities" violate the site parity by a ecting one site or bond, whereas \bondin purities", which modify two neighbouring bonds, violate the bond symmetry but respect the site parity. Bearing this in m ind, we use the name site- or bond-in purity. Note that this nam ing is di erent from the one used in [4] and [5], where an in purity on a single site is called site-in purity, and an in purity on a bond is called bondin purities, which we do not consider here, can be constructed using the Bethe-Ansatz [6]: Those defects are similar to bondin purities, but include also a coupling between the next-nearest neighbours around the in purity. Transparent in purities have also been studied extensively with analytic and num erical techniques during the last years, see for example [7] and [8]. As a result of Eggert and A eck, a site-in purity is relevant in the sense that it can break up a closed ring, whereas a bond-in purity is irrelevant, i. e. the defect is healed at low energies.

G apped spin system s containing intelevant in purities, i.e. in purities which do not close the gap in the system, are supposed to be equivalent to free D irac-ferm ions with random m ass, a m odel which has been widely investigated in one dimension [12, 13] in the context of doped spin-Peierls or spin-ladder systems and two dimensions [14] in the context of the Q uantum Hall E ect. However, the transformation to D irac ferm ions is valid only for special points in the parameter space, which correspond to the XY m odel (free ferm ions) for the dimension system, or the isotropic XXX-H eisenberg antiferrom agnet for the ladder m odel.

The num erical density m atrix renorm alization group [15] is a quasi-exact num erical m ethod to determ ine the ground state properties, in particular the ground-state energy, of long one-dim ensional (non-integrable) system s with reasonable accuracy. The bosonization technique [16] can be used with advantage to interpret the num erical data.

In the following, we introduce the models and the impurity types studied by us. U sing the bosonization technique and the Luttinger description, we then identify the leading non-linear operators, and classify the impurities according to them. The results for single defects are presented in Sec. 3. Concerning the dimerized system, we concentrate in our discussion on strong site- and bond-impurities. The results are discussed in Sec. 4, followed by a summary in Sec. 5.

2 M agnetic chains and spinless ferm ions

We begin by presenting the generic spin model, and then describe the equivalent ferm ionic model. Then we brie y introduce the Luttinger description, which is useful for discussing the relevant operators which lead to insulating behaviour.

2.1 The Heisenberg spin chain

As a starting point for the study of a general disordered spin-Peierls system in one dimension, we consider an anisotropic Heisenberg chain, given by the XXZ model, with a dimension interaction:

$$H_{spin} = \int_{i=1}^{X^{N}} J_{i}(u) = \int_{i=1}^{x} J_{i}(u) + \int_{i=1}^{x} J_{i+1}(u) + \int_{i=1}^$$

where the dimerization in the Peierls state, u, enters the coupling constant according to $J_i(u) = J[l + (P_u)^i u]$. For the clean XXZ model, i.e. for u = 0, and for zero totalm agnetisation, $M = {}_ih {}_i^z i = 0$, one nds three phases: a ferrom agnetic phase for 1, separated by a rst-order transition from a gapless phase for 1 < 1, whose low lying excitations are given by those of a Luttinger liquid; and an antiferrom agnetic phase for < 1. The transition from the Luttinger to the antiferrom agnetic phase is of B erezinskii-K osterlitz-T houless type. Adding the dimerization, u, the system become es localized by form ing spin-singlets on neighbouring sites for < 0, i.e. for antiferrom agnetic coupling. An excitation gap opens due to the usual Peierls mechanism [17]. Leaving aside the question whether a nite u can be stabilized, we note that the dimerization is already relevant for < 2=2 [18, 19], and the ground-state wave function is localized. The interaction-dimerization phase diagram was determined in [20].

In purities may be realized in three di erent ways. First, local magnetic elds may be present, resulting for example from magnetic in purities near the chain, which couple directly to the ^z-component at a speci c site. We call this kind of in purity a site-in purity. Second, the coupling between the spins may be modiled locally by a factor (1), for example by substituting Sr with La or Ge with Si in a spin chain compound like $La_x Sr_2 \ x C UO_3$ or $C UG e_1 \ x Si_x O_3$. As only one link is concerned this is similar to a local eld; nevertheless we call it link-in purity in the following. The third possibility is to modify both bonds to the left and to the right of the in purity site by an equalam ount, (1) : This situation, which is called bond-in purity, can be realized by doping magnetic in purities with spin 1/2 into a chain, e.g. substituting V by Nb. (Nevertheless, in some cases it is found that the free Nb-electron { with the spin { moves to the Vanadium site, i.e.a Nb⁵⁺ - and a V³⁺ -site is established instead of Nb⁴⁺ and V⁴⁺.) Completing the Ham iltonian (1) in this way, we can write

$$H_{spin} = \begin{array}{ccc} X^{N} & & X^{N} \\ J_{i}(u; ;b) & {}^{x}_{i} {}^{x}_{i+1} + {}^{y}_{i} {}^{y}_{i+1} + {}^{z}_{i} {}^{z}_{i+1} & h_{i} {}^{z}_{i}; \\ {}^{i=1} & {}^{i=1} \end{array}$$
(2)

with $J_i(u; b) = J_i(u) [1_{im} (im + im + 1)b]$, where m is a xed site.

2.2 The ferm ionic model

The corresponding ferm ionic model is obtained via the Jordan-W igner transform ation. In the result we change the notation, $J \ t$, $J \ t$, $J \ v=2$, and $_m \ 2h_m$, and neglect constant energy shifts, like $_i h_i$ and $(2N_f \ N=2)$, where N_f is the number

of ferm ions:

$$H_{\text{ferm ion}} = \begin{array}{c} X & X & X \\ t_i c_i^+ c_{i+1} + c_{i+1}^+ c_i & + & V_i n_i n_{i+1} + & i n_i \\ i & & i & i \end{array}$$
(3)

$$\frac{V}{2} [(n_m + n_{m+1}) + b(n_{m-1} + 2n_m + n_{m+1})]; \qquad (4)$$

where $t_i(u) = t[l + (1)^i u_t _{im t} (_{im} + _{im+1})b_t]$, and $V_i(u) = V [l + (1)^i u_V _{im V} (_{im} + _{im+1})b_V]$. Furtherm one, we have assumed that the coupling to (static) phonons and to the in purities can be varied independently in both the hopping and the interaction, by introducing six parameter $(u_t; u_V; t; v; b_t; b_V)$ instead of three (u; ;b). The particle density is $n_0 = N_f = N$, and we restrict ourselves to half lling; we set t = 1 in some of the form ulas below. As shown in [21], u_t is the main contribution arising from the dimerization, whereas $u_V = 0$. For simplicity, we likewise neglect (4) to avoid the mixing { in the fermionic picture { of bond- and site-im purity. In the case of the link-im purity, it was shown by M eden et al. [5] that the weakening of one bond in the spin model is equivalent to an impurity given by t and v, i.e. that the contribution (4) is of lesser importance. We assume that the same holds for the bond-im purity. The in this way simpli ed H am iltonian is then given by

Thus the link-impurity can occur as a pure hopping-impurity, $t \in 0$ and v = 0, or a generic link-impurity, $t \in 0$ and $v \in 0$. Setting t = 0, we can also realize an interaction-impurity by varying v. In the following we consider the H am iltonian given by Eq. (5) only.

2.3 Bosonization and Luttinger description

For the interpretation of the num erical data, we use the fact that in the gapless phase the system can be described by a Luttinger liquid, and that the distortions can be considered as a perturbation. In the bosonized form [16], the Ham iltonian can be written for the \clean" m odel as follows:

$$H_{boson} = \frac{dx}{2} + \frac{v}{g} \left[\theta_{x}'(x;t) \right]^{2} + vg \left[(x;t) \right]^{2}; \qquad (6)$$

where , is the momentum density conjugate to '(x;t), i.e. it corresponds to , = $@_t' = (vg)$ in the (Euclidean) path integral formulation of the theory. It is also related to the conjugate phase variable through , = $@_x$ (x)=. The velocity v of the bosonic excitations is given by v = [tsin(2)]=(2), and the interaction constant is g = =4, where parameterizes the interaction according to V = $2t\cos(2)$. The density (operator) is given by

$$n(x) = n_0 + \frac{\theta'}{\theta x} + \frac{k_F}{\theta} \cos [2k_F x + 2'(x)];$$
(7)

Ζ

We chose the above standard representation because then the order of the scattering process is directly seen in the non-linear term s. Non-linear { global and local { contributions arise from the dimerization and the interaction as well as from the impurities.

D in erization causes a
$$2k$$
-scattering process of the ferm ions,
Z
H_u / 2u dx sin [2' (x)]: (8)

W hile the ferm ion-ferm ion scattering with q=0 and $q=2k_{\rm F}$ is absorbed in the Luttinger-parameter g, the $4k_{\rm F}$ -scattering leads to

$$H_V / V dx \cos [4' (x) + (4k_F x G)x];$$
 (9)

where G is the reciprocal lattice vector. This term causes the transition to the CDW -state for V = 2 (g = 1=2).

Backscattering arises from a local potential (say at x = 0). Since the potential couples directly to the density, Eq. (7), we divide a nd in lowest order in the impurity strength

$$H = {}_{0}n_{0} / {}_{0}n_{2k_{\rm F}} (x = 0) / {}_{0} \cos[2' (0)];$$
(10)

A strong potential in an in nitely long chain is equivalent to a weak link [22]: The diagonalization of the above H am iltonian, H $_{\rm ferm\ ion}$ + H , leads, in the case of a strong potential between two sem i-in nite chains (R : right chain, L : left chain), to the contribution

$$H / \frac{c_{R}^{+}(0)c_{L}(0)}{0} / \frac{1}{0} \cos[2(0)]; \qquad (11)$$

A change in the hopping is also considered in the weak, t ! 0, and strong, t ! 1, limit. Following the analysis for the (weak) periodic [21] or random potential [23], we would assume that the transition from a site-centered potential to a bond-centered potential causes only a phase shift of =2 in the non-linear term, i.e. a shift from a cosine to a sine. The weak link thus should correspond to a high barrier, see again [22], i.e.

$$H_t / t \sin[2'(0)]; t! 0$$
 (12)

$$H_t / (1_t) \cos[2(0)]; t! 1$$
 (13)

should be appropriate descriptions. However, if we consider a modil ed link with H $_t$ / (1 $_t$) ($c_1^+ c_0^- + h:c:$), we indicate a modil ed link with

 $H_t / t \sin[7(0)]$ (14)

 $H_t / (1_t) \cos[(1) (0)]$: (15)

The local modi cation of the interaction, i.e. the interaction-in purity, leads to a $2k_F$ -contribution too, in addition to the $4k_F$ -term already present in Eq. (9):

$$H_v / H_t$$
 (16)

The modi cation of two links, in the lim it of $b = b_I + b_I + 0$, does not cause $2k_F$ -scattering at half lling. Thus, no non-linear contribution to the H am iltonian is found. In the lim it b! 1, however, we does not the following expression:

In the last step we use $(x) = _0 + x=L + (x)$, see [16], where $_0$ represents the zero-m ode contribution, x=L the boundary condition { see also the following section {, and (x) the excitations. In addition, the abbreviations ' (x)+ ' (x) = 2 (x), and (x) (0) = (x) are used.

2.4 The phase sensitivity

W e will use the phase sensitivity, i.e. the reaction of the system to a change in the boundary condition, to determ ine the localized-delocalized transition num erically for system s with nite size. W e m odel the di erent boundary condition via a magnetic

ux, penetrating the ring of the spinless ferm ions. The e ect of the magnetic ux results in an additional phase of the hopping terms, t_j ! $j_j je^{i_j}$, with < j < .The energy levels depend only on the total ux, = arg $\sum_{j=1}^{N} t_j$. In particular, we determ ine below the energy di erence between periodic ($Q_i = c_0$, = 0) and anti-periodic ($Q_i = c_0$, =) boundary conditions, $E = ()^{N_f} (E(0) - E())$. Here the factor ($1)^{N_f}$ cancels the odd-even e ects resulting from the change in the ground-state for odd versus even particle num bers. We recall that, for a clean system, the ground-state energy and the nite-size corrections can be obtained from the Bethe Ansatz [24]. At half lling (and for odd particle num ber), the result, in the Luttinger regime, is given by [25]

$$E_N$$
 () $N''_1 = \frac{V}{6N} \cdot 1 \cdot 3g \frac{2}{2}$; (18)

where "1 is the energy density in the therm odynamic limit. Thus N E = vg=2, independent of N, for the metallic state. In an insulator, on the other hand, we nd localized levels and the system cannot react to a twist in the boundary condition, i.e. N E is expected to decrease with system size. Considering the above model, in which the contributions of the local potential and the weakening of the neighbouring bonds are taken into account separately, the localized levels do not split o the continuous spectrum [26], and the phase sensitivity is an appropriate observable.



Fig. 1 Phase sensitivity as a function of interaction for a system with one site-in purity. The dashed-dotted lines correspond to Eq. (20), and the dashed lines to (21).

3 Comparison of site-and bond-im purities

3.1 Localpotential

A local magnetic eld, which corresponds to a local potential, is the well-known and most studied example of a site-in purity. In this case, the free motion of the fermions inside the ring is restricted by the back-scattering at the in purity ($k_F ! k_F$). As discussed by K ane and F isher [22] the in purity becomes transparent for an attractive, and completely relative for a repulsive interaction, according to the renormalization group equation

$$\frac{d_0}{dl} = (1 \quad g)_0:$$
(19)

In other words, the in purity strength scales either to zero or to in nity, for g > 1 and g < 1, respectively. The fact that an in purity scales to zero for repulsive interaction is con med by the scaling of a weak link [22]. For strong $_0$ the electric hopping is given by $t_t = 4t^2 = _0$. The nal result for the phase sensitivity is obtained by perturbation theory with respect to the defect strength, see [21] and [27], and is given by

$$N = \frac{vg}{2} = \frac{N}{N_0} \left(\frac{N}{N_0} \right)^{1/g}$$
(20)

in the weak scattering lim it, and by

$$N = \frac{4t^2}{j_0 j} \frac{N}{N_0} \int_{-1}^{1 = g} (21)$$

in the strong in purity limit, where N $_0$ 2 is a cut-o corresponding to a momentum cut-o of the order of the Ferm im on entum . As a sum mary, we show num erical data in Fig. 1. The most important result is that an intermediate defect strength scales to zero for attractive interaction, and to in nity for repulsive interaction, rather than scaling to an additional intermediate xed point.

3.2 Onemodied link

W e begin by checking whether the above expressions for the weak and strong potential, Eqs. (20) and (21), can be applied to the case of a modi ed link, as should be expected from the treatment in [22] or [23]. We therefore calculate the phase sensitivity for a weakly modi ed link, t = 0.2, and a weak link, t = 0.8. The results are shown in Fig. 2. However, the above expressions do not apply: Instead of Eq. (20) we do not for the weakly modi ed link

$$N = -\frac{vg}{2} + \frac{N}{N_0} + \frac{(1 g)^{-2}}{N}$$
(22)

This is actually the scaling according to Eq. (14). Therefore, Eq. (12) does not appropriately describe this in purity type. Sim ilarly, for the weak link, we do not recover Eq. (21), but instead

N E = 4 (1 t)
$$\frac{N}{2N_0}$$
 (1 1=g)=2 : (23)

In this case N ! N =2, as we connect two chains of length N =2.

Next we verify that the generic link-in purity can be written as a sum of a hoppingand an interaction-in purity, as the bosonized H am iltonians, Eqs. (14) and (16), suggest. As shown on the l.h.s. of Fig. 3, where the three cases: t = and v = 0, t = v, and v = and t = 0, are compared, this conjecture is indeed con rm ed. The qualitative behaviour is the same for all defect types. By comparing two di erent system sizes, we can x the transition point to V = 0 in all cases.

If the impurity is so strong that the sign of the hopping or the interaction changes, > 1, interaction dependent m axim a occur, in addition, for the generic link-impurity, see the r.h.s.ofFig. 3.

3.3 Bond-im purity

For the non-interacting system (V = 0) with one bond-in purity, it is easily seen that the back-scattering contributions, i.e. the Fourier components with q = 1 in the half-

led case, cancel each other as is the case for two site-in purities at an odd distance. For this reason, we presume that the phase sensitivity increases slightly with system size according to N $E / (1 2bN_0=N)$ also in the interacting system. For repulsive interaction the results of Eggert & A eck [3] show that this kind of perturbation is irrelevant and the system remains metallic. For an attractive interaction, the behaviour is expected to be similar. A coordingly, the results for integrable, triangle like defects [6] show that the phase sensitivity is slightly reduced for non-interacting fermions in



Fig. 2 Phase sensitivity as a function of interaction for a system with a hopping in purity. The straight line corresponds to the clean system, Eq. (18). The dashed lines correspond to Eq. (22), and the dashed-dotted lines to Eq. (23).



Fig. 3 Left: Phase sensitivity as a function of interaction for a system with one site-in purity of type t, tV, and V. R ight: D etails of the phase sensitivity as a function of interaction for a system with one strong link-in purity. The straight line corresponds to the clean case, the other lines are connecting the data points.



Fig. 4 Left: Phase sensitivity as a function of interaction for a system with one bond impurity of varying strength, the system size is N = 40. The lines correspond to $N = (b = 0)(1 \quad 2bl_0=N)$. Right: Phase sensitivity as a function of interaction for a system with one bond in purity of strength b = 0.5 (N = 40: +, N = 60: , N = 80: 4), and b = 0.9(N = 40: , N = 60: , N = 80:). The lines correspond to the saccording to Eq. (24).

the presence of such (transparent) in purities. In particular, a repulsive interaction leads to stronger suppression of the phase sensitivity than an attractive one.

The numerical data presented in the left part of Fig. 4 con m this assertion of an only slight reduction: clearly the system behaves metallic for smallb. However, by increasing the impurity strength, strong deviations are visible, already for b = 0.3 at V = 1.9. The value of the interaction, where this strong decrease is seen, m oves to a larger interaction when increasing the impurity strength, until the maximum reaches the repulsive regime for b > 0.7. U sing the scaling applicable for the weak link case, Eq. (21), t_t ! $t_t^e = t_t N^{1-1=g}$, a scaling relation for the two-weak-link case, given by the H am iltonian in Eq. (17), can be derived,

$$(1 b)! (1 b)_e / (1 b)N^{1 g=2 l= (4g)}$$
: (24)

A coording to this scaling relation, the weak links increase for V > 12. Thus, for an attractive interaction, there is an interaction value for which the phase sensitivity becomes independent of system size, while it scales to zero when further lowering the interaction down towards V = 2 (where the rst-order transition takes place in the clean system). Nevertheless, the system remains metallic in this region, but with a strongly reduced D rude weight. This behaviour, see the r.h.s. of Fig. 4, is di erent from the behaviour of an integrable defect (where a strong reduction arises for a repulsive interaction).



Fig. 5 Phase sensitivity versus interaction for a clean and a distorted dimerized system; the system size is N = 48. The lines correspond to Eq. (26).

4 Combination of dimerization and impurity

4.1 A barrier in a dim erized system

We combine now two perturbations and study rst a site-in purity in the dimerized system. For a rst impression, we calculate the energy levels and the ground-state energy of of non-interacting particles with an alternating hopping, following the treatment in [28], but adding one potential scatterer of strength . The ground-state energy is given by

$$E = 2t \frac{k_{\rm F}}{k_{\rm F}} \cos^2 ka + \frac{2}{4N^2} + u^2 \sin^2 ka / E()$$
(25)

with E () the second complete elliptic integral, where is given by $^2 = (1 u^2)=(1 + {}^2(N))$ 1 $u^2 {}^2(N)$; (N) = =2N. A single impurity in the non-interacting alternating chain was also discussed in [29]. Thus the phase sensitivity is given by, compare [20]:

N E = N E (0;0)
$$2N_0^p \frac{1}{u^2 + 2(N)} \frac{N}{N_0}^{2g}$$
: (26)

F igure 5 shows num erical data in comparison to this form ula, with N $_0$ 4 according to the cell doubling in the dimerized state.

The length dependence presently is not as clear as for a single in purity or for the clean dimerized system : For g < 1 the system is completely localized, the phase sensitivity decreases with system size, while for g > 2, the system appears to be delocalized. In between, for 1 < g < 2, however, a characteristic system size N $_c^2$ =



Fig. 6 Phase sensitivity as a function of interaction for a system with u = 0.1 and = 10. For V > 1 the phase sensitivity decreases with system size, and for V < 1.4 it increases. In between, it increases from N = 24 to N = 48, but decreases from N = 48 to N = 100.

 2 (g $~1)=[4u^2~(2~g)]$ can be de ned. For N smaller than $N_{\rm c}$, the phase sensitivity increases with N similar to the behaviour in the delocalized phase. Increasing the system size above N $_{\rm c}$, how ever, the phase sensitivity decreases, indicative of localization. This intermediate regime is shown in Fig. 6, where we plot the phase sensitivity for a set of parameters which clearly shows the described behaviour.

An impurity with weak or intermediate strength enlarges the delocalized region of the dimerized model, as already shown in [30]. For a strong barrier and a strong dimerization, a new feature is observed: In addition to the enlargement of the delocalized region a peak in the phase sensitivity is found in the localized regime, for

> 3 and u > 0.1. The characteristic behaviour is shown in Fig. 7, demonstrating that the increase for a value of V_{peak} 1 is already by one order of m agnitude for N = 100. The assumption that the impurity becomes irrelevant at V_{peak} is consistent

$u_V = 0$				$u_V = u_t$			
u		Vpeak	Vc	u		V_{peak}	Vc
0.1	10	(-1)	-1.3	0.1	10		-0.9
0.15	10	-1.1	-1.4	0.2	10		-1.3
0.2	10	-1.2	-1.6	0.3	10	-1.0	-1.45
0.25	10	-1.2	-1.7	0.5	10	-1.05	-1.65
0.3	10	-1.2	-1.8	0.7	10	-1.1	-1.75

Table 1 Values of V_{peak} and V_c for $u_V = 0$, and $u_V = u_t$. The latter case is included for completeness, compare the discussion in subsection 2.2, even though not mentioned separately in the text.



Fig. 7 Typical plot of the phase sensitivity versus interaction for a system with strong dimerization and a strong in purity.

with the initial increase of the phase sensitivity at this value. Since the e ect of the dimerization is weakened by an impurity, the following (by further lowering the interaction down to the value V_c) decrease of the phase sensitivity can be explained by the enhancement of the e ective dimerization, caused by the diminished in uence of the impurity. Lowering the interaction further, the dimerization becomes irrelevant, too, and the system delocalizes. Table 1 shows the characteristic interaction values for this model.

4.2 D in erization and bond-in purity

W hile we analyzed above a single site-in purity in a dimerized ring, we now concentrate on a single bond-in purity plus dimerization. Based on the results of Sec. 3.3, we expect that for a weak distortion the system still shows the phase transition at V =

 $\overline{2}$, with the delocalized region extending to V = 2. Increasing the strength of the bond-in purity, we also expect the unusual behaviour { as described above { for strong attractive interaction to occur in the dimerized system as well, because in this interaction regime the dimerization is irrelevant. The rst conjecture can be con med num erically for strong dim erization but small b. The num erical data for stronger distortion, i.e. for increasing b, show a more complex behaviour of the phase sensitivity, see Fig. 8. The rst observation is, similar to a site-in purity, that the transition to the metallic state occurs at weaker interaction strength, e.g. for u = 0.03 already at V = 1 (com pared to V) 1:5 in the undistorted case). A lso, the second conjecture is supported by the num erical data: For an interaction larger 1:5 the in uence of the bond-impurity drives the systems again to a than V m etallic state with a strongly reduced phase sensitivity. In between, 1.5 < V <1. the system ows to the free metallic xed point when increasing the system size.



Fig. 8 Phase sensitivity as a function of interaction for a dimerized (u = 0.03) system with a strong bond-in purity, b = 0.7; the system sizes are N = 20 and N = 60, respectively. For comparison, the data of the clean dimerized system, again for N = 20 and 60, are included.

5 Summary

O ur num erical studies of a one-dim ensional spin chain, which is equivalent to a system of spinless interacting ferm ions, with various distortions show that both types of siteim purities are irrelevant for an attractive interaction (using the ferm ion picture), and relevant for a repulsive one. The description within a rst-order perturbation treatm ent can be applied in the case of the site-im purity. The bond-im purity is irrelevant for repulsive interaction, and leads to a strong suppression of quantum coherence { but not to a localized ground-state for attractive interaction near the rst-order transition. The scaling could be determ ined using the bosonization technique. In the dim erized system, the num erical results show that dim erization and any kind of im purity weaken each other. A single barrier in a dim erized drain leads to an enhancem ent of the delocalized region com pared to the clean dim erized system . In addition, a sharp peak (as a function of the interaction param eter), increasing the phase sensitivity by one to two orders of m agnitude for small system s, N 100, is found for strong perturbations.

A bond-in purity in the dimerized system is irrelevant for a small in purity strength. A stronger in purity leads to a complicated phase diagram, especially for an attractive interaction. The combination of dimerization and impurity therefore leads in all cases to a shift of the localization-delocalization transition of the dimerized system to a weaker interaction strength. By tuning the values of dimerization and impurity strength, di erent metallic windows in the insulating system can be opened. At an interaction of about V 0.5;:::; 1 a bond-impurity turns the system into the metal. For a strong attractive interaction, V 1:5;:::; 2, where the bond-impurity reduces the D rude weight drastically, a strong site-impurity leads to delocalization, especially in the strongly dimerized system .

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